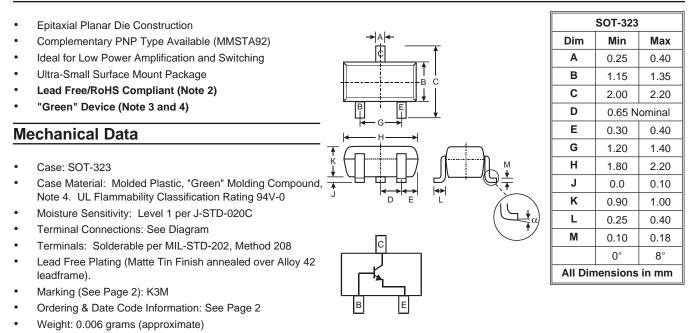




NPN SMALL SIGNAL SURFACE MOUNT TRANSISTOR

Features



Maximum Ratings @ T_A = 25°C unless otherwise specified

Characteristic	Symbol	Value	Unit							
Collector-Base Voltage	V _{CBO}	300	V							
Collector-Emitter Voltage	V _{CEO}	300	V							
Emitter-Base Voltage	V _{EBO}	6.0	V							
Collector Current (Note 1)	Ι _C	200	mA							
Power Dissipation (Note 1)	Pd	200	mW							
Thermal Resistance, Junction to Ambient (Note 1)	R JA	625	°C/W							
Operating and Storage and Temperature Range	Tj, TSTG	-55 to +150	°C							

Note: 1. Device mounted on FR-4 PCB, 1 inch x 0.85 inch x 0.062 inch; pad layout as shown on Diodes Inc. suggested pad layout

document AP02001, which can be found on our website at http://www.diodes.com/datasheets/ap02001.pdf.

2. No purposefully added lead.

3. Diodes Inc.'s "Green" policy can be found on our website at http://www.diodes.com/products/lead_freeindex.php.

4. Product manufactured with Date Code 0627 (week 27, 2006) and newer are built with Green Molding Compound. Product manufactured prior to Date Code 0627 are built with Non-Green Molding Compound and may contain Halogens or Sb2O3 Fire Retardants.



Electrical Characteristics @ T _A = 25°C unless otherwise specified									
旬"MMSTA42-7-El编编 maine	Symbol	Min	Max	Unit	Test Condition				
OFF CHARACTERISTICS (Note 5)									
Collector-Base Breakdown Voltage	V _{(BR)CBO}	300		V	$I_{\rm C} = 100 \mu A, I_{\rm E} = 0$				
Collector-Emitter Breakdown Voltage	V _{(BR)CEO}	300		V	$I_{\rm C} = 1.0 {\rm mA}, I_{\rm B} = 0$				
Emitter-Base Breakdown Voltage	V _{(BR)EBO}	6.0		V	$I_{E} = 100 \mu A, I_{C} = 0$				
Collector Cutoff Current	I _{CBO}		100	nA	$V_{CB} = 200V, I_E = 0$				
Collector Cutoff Current	I _{EBO}		100	nA	$V_{CE} = 6.0V, I_{C} = 0$				
ON CHARACTERISTICS (Note 5)									
DC Current Gain	h _{FE}	25 40 40							
Collector-Emitter Saturation Voltage	V _{CE(SAT)}		0.5	V	$I_{\rm C} = 20$ mA, $I_{\rm B} = 2.0$ mA				
Base-Emitter Saturation Voltage	V _{BE(SAT)}		0.9	V	$I_{\rm C} = 20 {\rm mA}, I_{\rm B} = 2.0 {\rm mA}$				
SMALL SIGNAL CHARACTERISTICS									
Output Capacitance	C _{cb}		3.0	pF	$V_{CB} = 20V, f = 1.0MHz, I_E = 0$				
Current Gain-Bandwidth Product	f _T	50		MHz	$V_{CE} = 20V, I_C = 10mA, f = 100MHz$				

Ordering Information (Note 4 and 6)

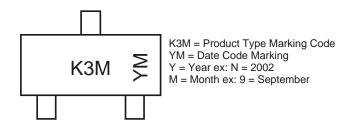
Device	Packaging	Shipping		
MMSTA42-7-F	SOT-323	3000/Tape & Reel		

Notes: 4. Product manufactured with Date Code 0627 (week 27, 2006) and newer are built with Green Molding Compound. Product manufactured prior to Date Code 0627 are built with Non-Green Molding Compound and may contain Halogens or Sb2O3 Fire Retardants.

5. Short duration pulse test used to minimize self-heating effect.

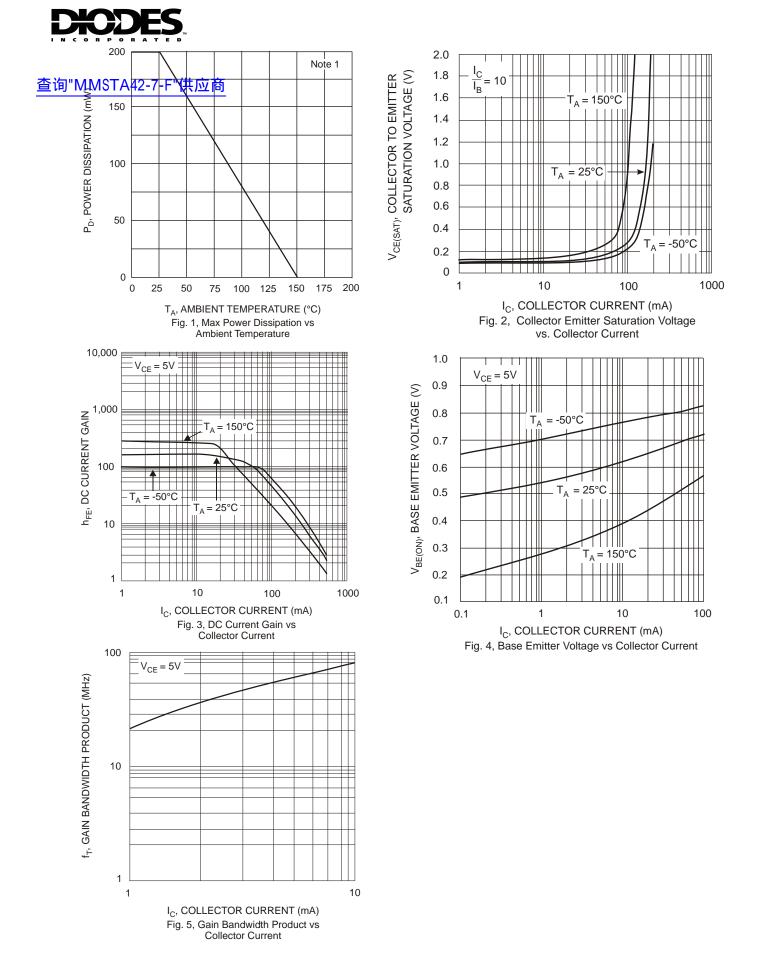
6. For Packaging Details go our website at http://www.diodes.com/datasheets/ap02007.pdf.

Marking Information



Date Code Key

Year	1998	199	9 2000	2001	2002	2003	2004	2005	2006	2007	2008	2009	2010	2011	2012
Code	J	K	L	М	N	Р	R	S	Т	U	V	W	Х	Y	Z
N	lonth		Jan	Feb	March	Apr	Мау	Jun	Jul	Aug	Sep	Oc	t	Nov	Dec
(Code		1	2	3	4	5	6	7	8	9	0)	Ν	D



DS30175 Rev. 9 - 2



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